2SC4692

Silicon NPN Triple Diffused

HITACHI

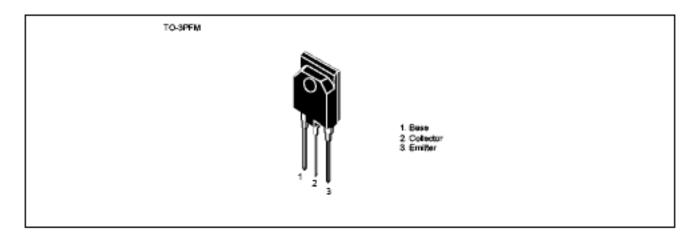
Application

EDTV/HDTV horizontal deflection output

Features

- High speed switching 0.5 μs Max
- High breakdown voltage V_{GBO} = 1500 V
- Isolated package; TO-3PFM

Outline



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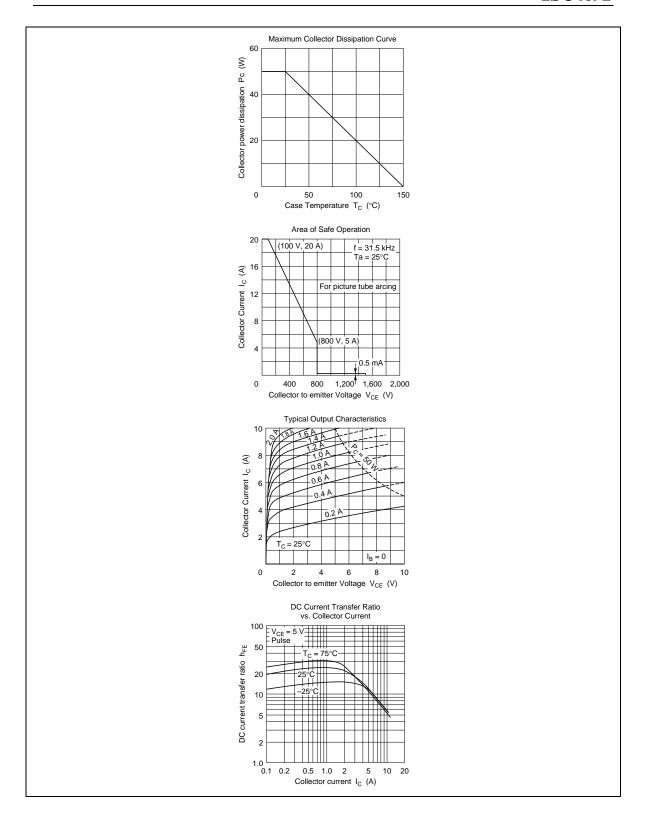
Absolute Maximum Ratings (Ta = 25°C)

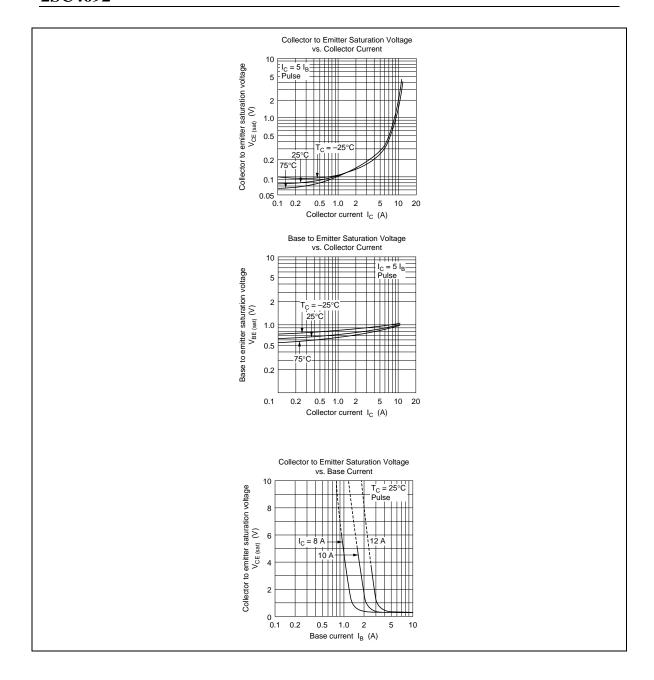
Item	Symbol	Ratings	Unit	
Collector to base voltage	V _{ceo}	1500	v	
Collector to emitter voltage	V _{oto}	800	V	
Emitter to base voltage	V _{ERO}	5	v	
Collector current	I _o	12	Α	
Collector surge current	I _{O (surge)}	20	Α	
Collector power dissipation	P _c ^{x1}	50	w	
Junction temperature	Ţj	150	°C	
Storage temperature	Tstg	-55 to +150	°C	

Note: 1. Value at T_o = 25°C.

Electrical Characteristics (Ta = 25°C)

Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to emitter breakdown voltage	V _{(BRICEO}	800	_	_	٧	I _e = 10 mA, R _{se} = _
Emitter to base breakdown voltage	V _{(BR)EBO}	5	_	_	V	$I_c = 10 \text{ mA}, I_c = 0$
Collector cutoff current	l _{ots}	_	_	500	μΑ	V _{cc} = 1500 V, R _{sc} = 0
DC current transfer ratio	h _{re}	15	_	35		V _{cp} = 5 V, I _c = 1 A
Collector to emitter saturation voltage	V _{CE (tat)}	-	_	5	V	I _c = 10 A, I ₈ = 2 A
Base to emitter saturation voltage	V _{BE (H4)}	_	_	1.5	٧	I _c = 10 A, I _g = 2 A
Fall time	t,	-	_	0.5	μs	I _{CP} = 8 A, I _{BI} = 1.4 A, I _{BZ} = -2.5 A





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HITACHI

Hitachi, Ltd.

Semiconductor & IC Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100, Japan Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

For further information write to: Hitachi America, Ltd.

Semiconductor & IC Div. 2000 Sierra Point Parkway Brisbane, CA. 94005-1835 U S A Tel: 415-589-8300 Fax: 415-583-4207 Hitachi Europe GmbH Electronic Components Group Continental Europe Dornacher Straße 3 D-85622 Feldkirchen München Tel: 089-9 91 80-0 Fax: 089-9 29 30 00 Hitachi Europe Ltd.
Electronic Components Div.
Northern Europe Headquarters
Whitebrook Park
Lower Cookham Road
Maidenhead
Berkshire SL6 8YA
United Kingdom
Tel: 0628-585000
Fax: 0628-778322

Hitachi Asia Pte. Ltd. 16 Collyer Quay #20-00 Hitachi Tower Singapore 0104 Tel: 535-2100 Fax: 535-1533

Hitachi Asia (Hong Kong) Ltd Unit 706, North Tower, World Finance Centre, Harbour City, Canton Road Tsim Sha Tsui, Kowloon Hong Kong Tel: 27359218 Fax: 27306071